PATENT NUMBER and **ISSUE DATE** U.S. UTILITY Pat nt Application CLASS SUBCLASS GAU APPL NUM **FILING DATE** 10020304 12/13/2001 438 2812 *APPLICANTS: Kapre Ravindra; Hsiao Tommy; Wang Yanhua; Min Kyungjin; **CONTINUING DATA VERIFIED: BEST AVAILABLE COPY * FOREIGN APPLICATIONS VERIFIED: RESCIND -PG-PUB DO NOT FUBLISH 🗵 ATTORNEY DOCKET NO Foreign priority claimed 🛘 yes 🕽 no 35 USC 119 conditions met 🗅 yes 🗆 no 01-721/LSI1P185 Verified and Acknowledged Examinors's infials TITLE: Buried channel devices and a process for their fabrication simultaneously with surface channel devices to produce transistors and capacitors with multiple electrical gate exides US.DEPT OF COMM.PAT & TM-PTO-436L(Rev. 12.94) **CLAIMS ALLOWED** NOTICE OF ALLOWANCE MAILED Print Claim for O.G Total Claims Assistant Examiner DRAWING ISSUE FEE Sheets Drwg. Figs.Drwg. Print Fig. **Amount Due Date Paid** Primary Examiner Application Examiner TERMINAL PREPARED FOR ISSUE WARNING: The information disclosed herein may be restricted. DISCLAMER Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark

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